The thermal decomposition of barium trifluoroacetate thin films

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Abstract

The thermal decomposition of barium trifluoroacetate thin films under different atmospheres is presented. Thermogravimetry and evolved gas analysis have been used for this \textit{in situ} analysis. We focus our attention on the different behavior exhibited by films when compared to powders. The decomposition of barium trifluoroacetate is altered due to the faster out-diffusion of the product reaction :CF\textsubscript{2}. After barium trifluoroacetate decomposition a stable intermediate, barium fluoride, is formed. The decomposition of barium fluoride is diffusion controlled and depends on water partial pressure.

Keywords: barium trifluoroacetate, BaTFA, barium fluoride, thin films, thermal decomposition, TG, EGA, mass spectrometry.

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1. Introduction

Chemical solution deposition (CSD) is an efficient, flexible, low cost and scalable method for the fabrication of functional oxide films [1-3]. CSD involves solution preparation, solution deposition, a low temperature thermal treatment to remove the organic species and a high temperature thermal treatment to crystallize the amorphous films. Thermal analysis (TA) is especially suited to analyzing the low temperature treatment due to its ability to monitor in situ the processes that take place during precursor decomposition as well as their dependence on the treatment conditions: temperature program and oxygen and water partial pressures [4-9]. Knowledge of the transport mechanism that affects the thermal decomposition of the organic precursor is essential for CSD processing [10-12].

Although CSD is used to synthesize films, TA is routinely performed on powders, TA analysis on films is very scarce. In general, the main reason for this is that the signal measured by TA techniques is proportional to the sample mass. For instance, typical sample masses for thermogravimetric measurements on powders are around 10 mg whereas film masses are, at best, one order of magnitude smaller. In addition, precursor decomposition usually involves solid-gas reactions that strongly depend on transport phenomena: in-diffusion of reactants, out-diffusion of products or heat dissipation in exothermic processes. As a result, the behavior of powders may strongly differ from the actual behavior of films [13-16].

In this paper we will analyze the thermal decomposition of barium trifluoroacetate, Ba(CF$_3$COO)$_2$ (Ba(TFA)$_2$), in the form of films. Ba(TFA)$_2$, combined with yttrium and copper precursors, is the most common precursor in the fabrication of high-performance YBa$_2$Cu$_3$O$_{7-\delta}$ (YBCO) superconducting films [12,17,18]. Thermogravimetry (TG) is used to monitor the decomposition process. A mass spectrometer (MS) is used to perform the evolved gas analysis (EGA) of volatiles formed during decomposition. Intermediate and final products are characterized using scanning electron microscopy (SEM), energy dispersive X-ray micro-analysis (EDX) and X-ray diffraction (XRD). Different atmospheres have been tested. We will show that Ba(TFA)$_2$ films decompose differently to powders [19-21] and that BaF$_2$ decomposition kinetics is controlled by HF diffusion.

2. Experimental
The synthesis of barium trifluoroacetate $\text{Ba(CF}_3\text{COO)}_2$ powders is described in ref. [21]. A solution 0.56 M of $\text{Ba(TFA)}_2$ in anhydrous methyl alcohol was obtained at room temperature by manually shaking the mixture for less than 1 minute. Films were prepared by manually freely spreading microdrops (~2 µL) on the surface of a glass disc (12 mm in diameter) or on a square LAO plate (10×10 mm$^2$). The solvent was removed by heating the substrate at 70ºC for 15 minutes in a hot plate under vacuum. After solvent evaporation, the masses of the films vary from 0.21 to 2.0 mg.

TG analysis was performed with a Setaram apparatus model, Setsys Evolution 16. To improve the signal-noise ratio, two substrates coated on both sides were analyzed simultaneously. Gas flow was controlled by mass flow meters. High-purity nitrogen, argon, oxygen and synthetic air were used. Water-saturated gases were obtained by bubbling the carrier gas in water at standard temperature and pressure (25ºC, 1 atm). TG curves were corrected by subtracting a consecutive identical second measurement that was performed without opening the furnace to ensure that the differences between the first and second measurements were minimal. In addition, the mass of the final residue was measured at room temperature with an analytical balance that allows us to determine the absolute mass with accuracy better than 5 µg. Then, the TG curve is vertically shifted so that the final mass of the TG curve coincides with that measured at room temperature. Residual oxygen and water partial pressures on the furnace were 0.01% and 0.002%, respectively. Simultaneous TG and EGA analyses were performed with a Mettler Toledo, model TGA851eLF, thermobalance coupled to an MKS quadrupole mass spectrometer (Microvision Plus). Residual oxygen and water partial pressures on the TGA851eLF furnace were 0.2% and 0.04%, respectively. Complementary EGA analyses were performed by placing the samples inside a quartz tube at a pressure of around 10$^{-6}$ mbar. Samples were heated using an external furnace. Thermal analysis experiments were performed at heating rates of 5, 10 and 20 K/min.

XRD experiments were done in a SMART APEX diffractometer from Bruker AXS. The X-ray beam wavelength was 0.710730Å (Mo-Kα). The X-ray source was operated at a voltage of 50 kV and a current of 3 mA. SEM and EDX observations were performed in a Zeiss DSM 960A scanning electron microscope operated at 20 kV. Samples were coated with a thin gold or carbon films to remove electrostatic charges.

3. Results
In Figs. 1 and 2 we have plotted the mass variation when Ba(TFA)$_2$ films are heated at 20 K/min in dry and wet atmospheres with different oxygen content. The mass loss evolution can be divided into three stages. The first stage (below 150ºC) corresponds to dehydration. The larger mass loss takes place at the second stage, which starts at 220ºC and is related to precursor decomposition. The mass of the solid residue after precursor decomposition remains constant in a wide temperature range and corresponds to the expected mass of BaF$_2$: 

$$m[\text{BaF}_2]/m[\text{Ba(CF}_3\text{COO)}_2]\cdot 100 = 48.25\%.$$  

(1)

The formation of BaF$_2$ has been confirmed by XRD analysis. Fig 3 shows that the product, when films are heated up to 400ºC at 20 K/min in dry and wet argon and air atmospheres, is mainly crystalline BaF$_2$. The formation of BaF$_2$ instead of BaO or BaCO$_3$ is due to the high electronegativity of fluorine which displaces the oxygen bonded to Ba [18].

SEM analysis of the films obtained under different atmospheres has revealed that the thickness is quite inhomogeneous (see Fig. 4.a). This result is not surprising if we take into account that the solution deposition method (drop coating) results in inhomogeneous films due to the enhanced solvent evaporation at the rim of the deposited layer: the so-called “coffee ring effect” [22-24]. The thickness may vary a factor of two from the central region to the rim of the film. In addition, the actual film density is significantly smaller than the bulk density of BaF$_2$. For instance, from Fig. 4.a, one can determine the film thickness which is around 1.6 µm whereas from the mass of this film we have obtained a rough estimation of the film density, 2.6 g/cm$^3$ which is significantly smaller than that of bulk BaF$_2$ ($\rho$(BaF$_2$)=4.89 g/cm$^3$). As to the microstructure, we have not observed any significant differences between the films obtained under different atmospheres (see Figs. 4b and 4.c).

Contrarily to the results reported in the literature for powders [20,21], the decomposition of films does not exhibit any dependence on the oxygen or water partial pressure. This can be clearly observed in the insets of Figs. 1 and 2, where curves obtained under different oxygen and water partial pressures overlap. Especially remarkable, is the nearly perfect overlapping in the case of dry atmospheres.

In Fig 5 we have plotted the main volatiles formed during Ba(TFA)$_2$ decomposition. EGA has been carried out in vacuum (10$^{-6}$ mbar). EGA reveals two different steps. In that of below 325ºC, similar amounts of CO$_2$ and CO are formed
([CO$_2$]$^+$ (m/z=44) and [CO]$^+$ (m/z=28)). In this first step the more abundant volatile containing fluorine is CF$_3$CFO (In ref. [21], ions [CF$_3$]$^+$ (m/z=69) and [COF]$^+$ (m/z=47) were assigned to the formation of CF$_3$CFO) whereas when above 325ºC the larger amount of volatiles is formed. This second step is characterized by a significantly larger quantity of CO$_2$ (approximately twice the amount of CO) and the more abundant volatile containing fluorine is the difluorocarbene molecule, :CF$_2$ (ions [CF]$^+$ (m/z=31) and [CF$_2$]$^+$ (m/z=50)).

This tendency is also observed in measurements carried out at atmospheric pressure. In Fig 6 we have plotted the result of the simultaneous TG-EGA analysis of a very thick film. The EGA sensibility for films is significantly reduced, with respect to powders, because of the smaller mass and the larger surface that results in a higher gas dilution. Thus, to perform the simultaneous TG-EGA, we are forced to work with very thick films. When compared to powders [21], in Fig. 6 we observe larger quantities of :CF$_2$ and the amount of CO$_2$ is significantly larger than that of CO. However, compared to the EGA analysis in vacuum the differences, with respect to powders, are less pronounced.

According to the mechanisms proposed for powders in ref. [21], the decomposition of Ba(TFA)$_2$ is initiated by the two consecutive reactions:

\[(CF_3COO)_2Ba \leftrightarrow CF_3COOBaF + :CF_2 + CO_2 \tag{2}\]

\[CF_3COOBaF + :CF_2 \leftrightarrow BaF_2 + CF_3CFO + CO \tag{3}\]

Note that reactions (2) and (3) involve the formation of equal amounts of CO and CO$_2$, and the formation of CF$_3$CFO as the main volatile containing fluorine, is in agreement with the EGA results for the first decomposition step. However, the second step involves a larger formation of CO$_2$ and :CF$_2$. This scenario is compatible with the reaction [20]:

\[CF_3COOBaF \leftrightarrow BaF_2 + :CF_2 + CO_2 \tag{4}\]

Thus, two different mechanisms compete for the decomposition of CF$_3$COOBaF, reactions (3) and (4). While the decomposition is initiated by reaction (3), during the decomposition reactions (3) and (4) coexist. In the case of thin films in vacuum, reaction (4) is clearly enhanced, being the main decomposition path above 325ºC (see Fig. 5).

The last stage at high temperature (~1200ºC) corresponds to the decomposition of BaF$_2$. EDX shows that the final solid residue contains barium and oxygen but the final mass of the solid residue is below the expected mass for metallic Ba, thus some Ba
is volatilized at the last decomposition stage. TA measurements in powders [20,21] have stated that BaF\(_2\) is stable up to 1200°C (in dry or wet atmospheres). From Fig. 1, one can observe that, in films and in wet atmosphere, BaF\(_2\) decomposition temperature is shifted down to around 100°C. Also, in Fig. 7, one can observe that, for a given thickness, films decompose at a lower temperature in the presence of water. Thus, the analysis on films shows that BaF\(_2\) decomposition is controlled by diffusion, and that water plays a key role in its decomposition.

Transformations controlled by gas diffusion exhibit a dependence on the film thickness [25]. In Fig 7 one can observe that the thicker the films (larger mass) are, the higher the BaF\(_2\) decomposition temperature is. Since the distance of diffusion is significantly longer in powders, their decomposition temperature is shifted to higher temperatures (see Fig. 1). Therefore, in the case of solid-gas reactions, films may decompose at significantly lower temperatures than powders. This means that decomposition temperatures drawn from TA experiments on powders may significantly differ from their actual values in films [13,14,16].

Conversely, in Fig. 7 we do not observe any dependence of the decomposition temperature of Ba(TFA)\(_2\) on the film thickness (~350°C). This result would indicate that, in the thickness range examined, kinetics is not controlled by diffusion of reactive or product gases. This result is in agreement with the observed independence of the reaction kinetics on the oxygen and water partial pressures, previously reported. Again, this result is in contrast with the observed behavior in powders [21].

4. Discussion

Contrarily to powders, the decomposition of Ba(TFA)\(_2\) in films does not exhibit any dependence on the oxygen partial pressure. In powders [21], the dependence on the oxygen partial pressure was explained in terms of reaction (3); reaction (3) results in the formation of CO, thus an accumulation of CO in the voids between particles may reduce the decomposition kinetics. The presence of O\(_2\) provides an efficient path to decrease the local partial pressure of CO, thus it enhances the decomposition rate. In the case of films, the large surface to volume ratio significantly facilitates the CO removal and accordingly, the presence of oxygen to boost the reaction is no longer necessary. Therefore, no influence on the oxygen partial pressure is observed.

In the case of powders [21] two different mechanisms were proposed to explain the dependence on the p(O\(_2\)): the removal of CO and the local overheating related to CO
combustion. If the main reason for the lower temperature decomposition in the presence of $O_2$ were the local overheating, one would expect a higher temperature decomposition in films due the absence of local overheating in films [15,16]. Note that, due to the local overheating in powders, the decomposition temperature increases when the sample mass is reduced (see Fig. 6 in ref. [21]). However, Fig. 1 shows that films decompose at lower temperatures than powders. This lower temperature decomposition in films is due to the enhanced gas transport. One should be very careful when extrapolating from the behavior observed in powders for small sample masses, to films.

In both films and powders, reactions (3) and (4) are two competing mechanisms for the decomposition of $CF_3COOBaF$. Difluorocarbene, $:CF_2$, is a reactive in reaction (3) while it is a product in reaction (4). Thus, a high concentration of $:CF_2$ would promote reaction (3) against reaction (4), while a low concentration of $:CF_2$ would do just the opposite. In the case of powders, the trapped $:CF_2$ makes reaction (3) the dominant path. On the contrary, in films outdiffusion of $:CF_2$ is much faster, hence reaction (4) is the main decomposition path (in the case of vacuum, the removal of $:CF_2$ is further promoted). Essentially, the lack of dependence of the $Ba(TFA)_2$ decomposition kinetics in the film thickness confirms that $:CF_2$ is efficiently removed.

It is important to note in the case of powders that, the formation of local atmospheres in the interstices between particles may alter the reaction kinetics, promoting secondary reactions of reaction products and may result in a spatially inhomogeneous reaction [15]. Conversely, in-transpo rt of reactive gas and out-transport of reaction volatiles in films is clearly enhanced. Therefore, in general, TA in films allows a better understanding of the intrinsic kinetics of solid-gas reactions.

It is generally assumed that fluorides decomposition is governed by the reaction:

$$BaF_2 + H_2O \leftrightarrow BaO + 2HF,$$

and that the kinetics is controlled by the out-diffusion of HF. Therefore, due to the enhanced diffusion in films, with respect to powders, decomposition in films takes place at significantly lower temperature (around 100ºC lower). We have also observed that the kinetics depend on the $p(H_2O)$ being significantly enhanced in the presence of water, in agreement with reaction (5). However, despite the fact that $BaF_2$ decomposition is significantly enhanced in films, its decomposition temperature is still too high to understand the YBCO formation. Metal TFAs are used in the synthesis of YBCO to prevent the formation of the highly stable $BaCO_3$ [12,18,26,27]. However, the high stability of $BaF_2$ is in contrast to the formation of YBCO below 800ºC. It has been
proposed [12] that after precursor decomposition, a barium yttrium fluoride is formed that will decompose at a much lower temperature than BaF$_2$, thus allowing the formation of YBCO. Nonetheless, our TA measurements in films show that film thickness, water partial pressure and gas flow are key parameters in controlling the fluoride decomposition and eventually the quality of YBCO films, as stated by several authors [10,12,18]. It is also noteworthy that BaF$_2$ decomposition takes place in dry atmosphere as well, albeit at a higher temperature (Fig. 7). The reason being, that reaching inert conditions in films is much more difficult to achieve due to their high surface to volume ratio. In our case, the residual water partial pressure ($p(H_2O)<0.002\%$) is sufficient to decompose BaF$_2$ but at a significantly lower rate when compared to wet conditions. It is worth noting that we have not observed BaF$_2$ decomposition in powders and dry atmosphere.

5. Conclusions

Thermal decomposition of barium trifluoroacetate films under different atmospheres has been analyzed. Differences between the behavior in films and powder have been highlighted and analyzed. Due to the shorter diffusion path and to the higher surface to volume ratio, heat and gas renewal and transport is clearly enhanced in films. As a result, the observed behavior in films strongly differs from that of powders. We have observed different decomposition temperatures, different atmosphere dependences and the main decomposition mechanism is also modified.

In particular, Ba(TFA)$_2$ decomposition does not depend on the oxygen and water partial pressure. The decomposition is initiated by a mechanism that entails the formation of CO, CO$_2$ and CF$_3$CFO, however, the main decomposition path involves the formation of CO$_2$ and :CF$_2$.

The solid residue after Ba(TFA)$_2$ is face-centered cubic BaF$_2$. In the presence of water, BaF$_2$ decomposes at around 1200ºC. The decomposition of BaF$_2$ is controlled by HF out-diffusion and thus gas flow, film thickness and water partial pressure are key parameters to control the decomposition of BaF$_2$.

Our results indicate that the actual behavior on films may strongly differ from that of powders, i.e., in general, the conclusion drawn from the TA of metal organic precursors in the form of powders cannot be extrapolated to film synthesis through chemical solution deposition. Besides, TA in films opens up new perspectives to the contribution of TA in the synthesis of advanced oxides films through chemical methods.
Finally, TA of solid-gas reaction in thin films allows for a better understanding of the intrinsic kinetics of the reactions that take place.

**Acknowledgements**

This work was partially funded by the Spanish *Programa Nacional de Materiales* through projects MAT2011-28874-C02-01 and MAT2011-28874-C02-02, by the Consolider program Nanoselect, CSD2007-00041, EU project NESPA-RTN and by the *Generalitat de Catalunya* contracts No. 2009SGR-185 and 2009SGR-770. H. Eloussifi acknowledges the financial support of the Tunisian Ministry of Higher Education and Scientific Research.
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Figure 1. TG curves for thermal decomposition of Ba(TFA)$_2$ films heated at 20 K/min in wet atmospheres with different oxygen partial pressures: air (21%), nitrogen and oxygen mixture (80% O$_2$) and argon (0.02%) and powders in wet air. Precursor masses per unit surface of a single film, $m_S$, are 1.14, 1.15 and 1.19 mg/cm$^2$ respectively. The initial sample mass of powders was 18 mg. The mass has been normalized to the mass after dehydration. Inset: detail of the precursor film decomposition for wet and dry atmospheres and for different oxygen partial pressures.
Figure 2. TG curves for thermal decomposition of Ba(TFA)$_2$ heated at 20 K/min in dry atmospheres with different oxygen partial pressures: air (21%, dotted line), nitrogen and oxygen mixture (80% O$_2$, dashed line) and argon (0.02%, solid line). Values of $m_s$ are 0.98, 1.44 and 1.29 mg/cm$^2$ respectively. The mass has been normalized to the mass after dehydration. Horizontal dotted line is the expected final mass for the formation of BaF$_2$. Inset: detail of the precursor decomposition.
**Figure 3.** X-ray powder diffractograms of solid residues after heating the Ba(TFA)$_2$ to 400°C at 20 K/min in different atmospheres. Triangles: face-centered BaF$_2$ phase [28].
Figure 4. Scanning electron micrograph obtained when a Ba(TFA)$_2$ film, $m_s$=0.98 mg/cm$^2$, is heated to 400°C at a constant rate of 20 K/min in wet argon (a), synthetic air (b) and dry argon (c).
Figure 5. EGA analysis of thermal decomposition of Ba(TFA)$_2$ in vacuum ($10^{-6}$ mbar), $m_s=0.98$ mg/cm$^2$. Heating rate is 5 K/min. Only the more intense ions have been plotted.
Figure 6. Simultaneous TG-EGA analysis of thermal decomposition of Ba(TFA)$_2$ in dry argon for a very thick film ($m_S=5.24$ mg/cm$^2$). EGA curves correspond to the more intense ions. Heating rate is 20 K/min. To facilitate the comparison, some curves have been rescaled by a factor 4 (x4).
Figure 7. TG curves for thermal decomposition of Ba(TFA)$_2$ heated at 20 K/min in wet (solid lines) and dry (dashed lines) synthetic air (p(O$_2$)=21%). The mass has been normalized to the mass after dehydration. Horizontal dotted line is the expected final mass for the formation of BaF$_2$. Precursor mass per unit surface of a single film is indicated.